## NSN 5961-01-468-7631

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-468-7631 **Inclosure Material:** Glass **Overall Length:** 74.900 millimeters **Terminal Length:** 8.900 millimeters **End Application:** E/ifscm joint strs rd **Mounting Facility Quantity: Mounting Method: Terminal Terminal Circle Diameter:** 5.460 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5000.0 working peak off-state voltage **Current Rating Per Characteristic:** 40.00 amperes zero-gate-voltage source current any acceptable **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** High voltage power rectifier, fast recovery **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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